Ordering number: EN2535

PNP/NPN Epitaxial Planar Silicon Transistors



2SA1606/2SC4159

High-Voltage Switching, AF 100W Driver Applications

Applications

· High-voltage switching, AF power amplifier, 100W output predrivers.

Features

· Micaless package facilitating mounting.

(): 2SA1606

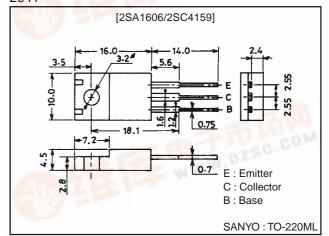
Specifications

Absolute Maximum Ratings at Ta = 25°C

Package Dimensions

unit:mm

2041



Parameter	Symbol	Conditions	Ratings	Unit	
Collector-to-Base Voltage	V _{CBO}		(–)180	V	
Collector-to-Emitter Voltage	VCEO		(-)160	V	
Emitter-to-Base Voltage	V _{EBO}	110	(–)6	V	
Collector Current	IC		(–)1.5	Α	
Collector Current (Pulse)	I _{CP}	a total Villam and	(–)3	Α	
Collector Dissipation	PC	Tc=25°C	15	W	
Junction Temperature	Tj	- 1 - N/A	150	°C	
Storage Temperature	Tstg	TIME BUILD	-55 to +150	°C	

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =(-)120V, I _E =0			(–)10	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =(-)4V, I _C =0			(-)10	μΑ
DC Current Gain	h _{FE}	V _{CE} =(-)5V, I _C =(-)300mA	60*	LTT	200*	- 14
Gain-Bandwidth Product	f _T	V _{CE} =(-)10V, I _C =(-)50mA	- 123	100	40.	MHz
Output Capacitance	C _{ob}	V _{CB} =(-)10V, f=1MHz		(30)23		pF
Base-to-Emitter Voltage	V _{BE}	V _{CE} =(-)5V, I _C =(-)10mA	W		(–)1.5	V

*: The 2SA1606/2SC4159 are classified by 300mA h_{FE} as follows:

60 D 120 100 E 200

Continued on next page.

- Any and all SANYO products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your SANYO representative nearest you before using any SANYO products described or contained herein in such applications.
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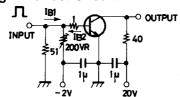
SANYO Electric Co.,Ltd. Semiconductor Bussiness Headquaters
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

2SA1606/2SC4159

Continued from preceding page.

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =(-)500mA, I _B =(-)50mA		(-0.5)		V
				0.3		V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =(-)1mA, I _E =0	(–)180			V
Collector-to-Emitter Breakdown Voltage	V _(BR) CEO	I _C =(-)1mA, R _{BE} =∞	(–)160			V
Emitter-to-Base Breakdown Votage	V _{(BR)EBO}	I _E =(-)1mA, I _C =0	(–)6			V
Turn-ON Time	ton	See specified test circuit.		(0.29)		μs
		See specified test circuit.		0.15		μs
Fall Time	t _f	See specified test circuit.		(0.19)		μs
		See specified test circuit.		0.48		μs
Storage Time	t _{stg}	See specified test circuit.		(0.48)		μs
		See specified test circuit.		0.81		μs

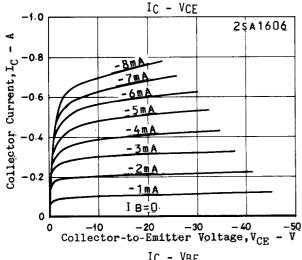
Switching Time Test Circuit

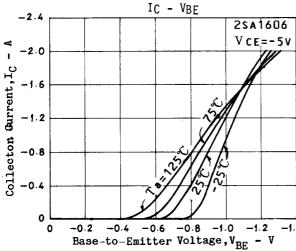


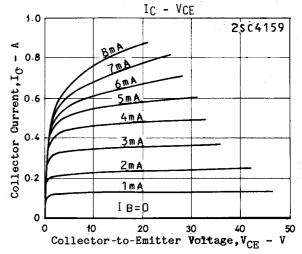
 $10I_{B1} = -10I_{B2} = I_C = 0.5A$

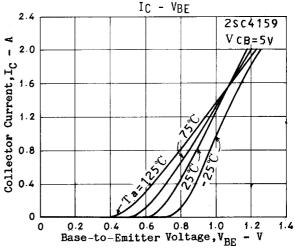
PW=20μs

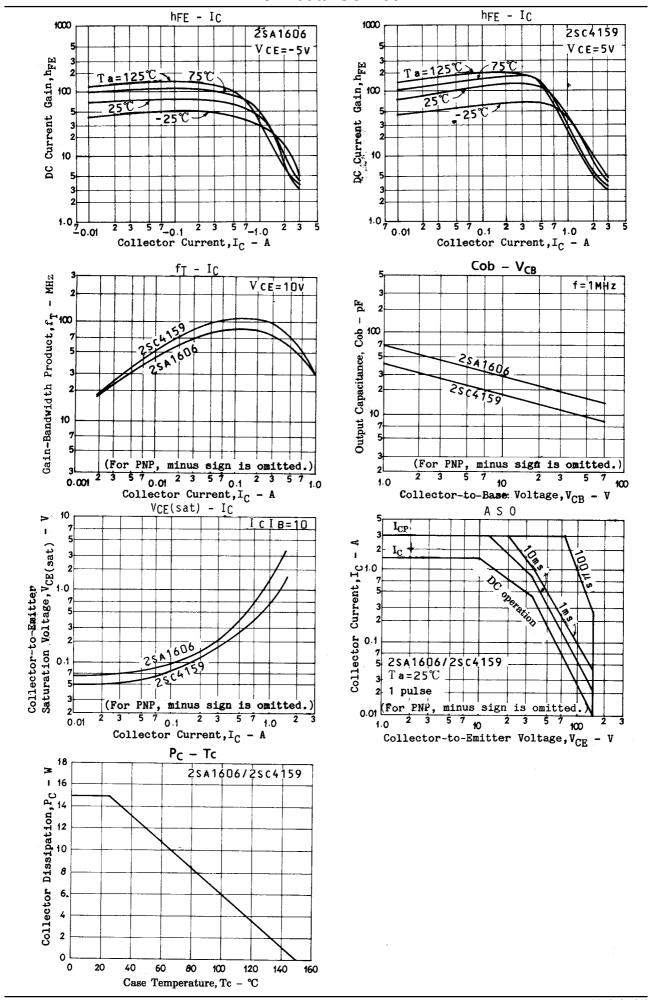
For PNP, the polarity is reversed. Unit (resistance : Ω , capacitance : F)











2SA1606/2SC4159

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